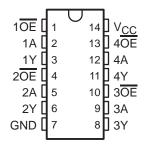
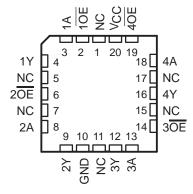
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- State-of-the-Art Advanced BiCMOS Technology (ABT) Design for 3.3-V Operation and Low-Static Power Dissipation
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V<sub>CC</sub>)
- Support Unregulated Battery Operation Down to 2.7 V
- Typical V<sub>OLP</sub> (Output Ground Bounce)
  < 0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17
- Bus-Hold Data Inputs Eliminate the Need for External Pullup Resistors
- Support Live Insertion
- Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK), and Ceramic (J) DIPs

#### SN54LVT125 . . . J PACKAGE SN74LVT125 . . . D, DB, OR PW PACKAGE (TOP VIEW)



# SN54LVT125 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

#### description

These bus buffers are designed specifically for low-voltage (3.3-V)  $V_{CC}$  operation, but with the capability to provide a TTL interface to a 5-V system environment.

The 'LVT125 feature independent line drivers with 3-state outputs. Each output is in the high-impedance state when the associated output-enable  $(\overline{OE})$  input is high.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN74LVT125 is available in TI's shrink small-outline package (DB), which provides the same I/O pin count and functionality of standard small-outline packages in less than half the printed-circuit-board area.

The SN54LVT125 is characterized for operation over the full military temperature range of  $-55^{\circ}$ C to 125°C. The SN74LVT125 is characterized for operation from  $-40^{\circ}$ C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

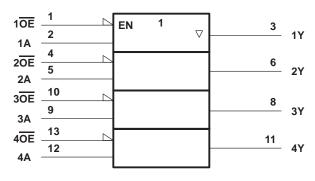


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#### **FUNCTION TABLE** (each buffer)

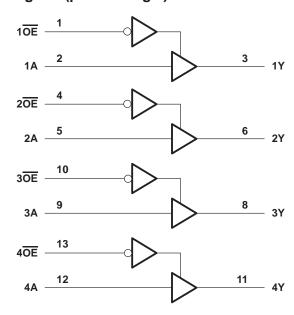
INP	JTS	OUTPUT
OE	Α	Υ
L	Н	Н
L	L	L
Н	Χ	Z

## logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

## logic diagram (positive logic)



Pin numbers shown are for the D, DB, J, and PW packages.

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
  - 2. This current flows only when the output is in the high state and  $V_O > V_{CC}$ .
  - 3. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils. For more information, refer to the Package Thermal Considerations application note in the 1994 ABT Advanced BiCMOS Technology Data Book, literature number SCBD002B.



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#### recommended operating conditions (see Note 4)

						SN74LVT125	
			MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage		2.7	3.6	2.7	3.6	V
VIH	High-level input voltage		2	EN	2		V
V <sub>IL</sub>	Low-level input voltage			0.8		0.8	V
VI	Input voltage		,<	5.5		5.5	V
IOH	High-level output current		(5)	-24		-32	mA
loL	Low-level output current		ìq	48		64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	8	10		10	ns/V
TA	Operating free-air temperature		-55	125	-40	85	°C

NOTE 4: Unused control inputs must be held high or low to prevent them from floating.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS				154LVT1	25	SN74LVT125			UNIT		
PARAMETER	'	MIN	TYP†	MAX	MIN	TYP†	MAX	UNII				
VIK	$V_{CC} = 2.7 \text{ V},$	$I_{I} = -18 \text{ mA}$			-1.2			-1.2	V			
	$V_{CC} = MIN \text{ to } MAX^{\ddagger},$	I <sub>OH</sub> = -100 μA	V <sub>CC</sub> -0.2			V <sub>CC</sub> -0.2						
\/a	$V_{CC} = 2.7 \text{ V},$	$I_{OH} = -8 \text{ mA}$	2.4			2.4			V			
VOH	V <sub>CC</sub> = 3 V	$I_{OH} = -24 \text{ mA}$	2						V			
	VCC = 3 V	$I_{OH} = -32 \text{ mA}$					2					
	V <sub>CC</sub> = 2.7 V	I <sub>OL</sub> = 100 μA				0.2			0.2	2		
	VCC = 2.7 V	$I_{OL} = 24 \text{ mA}$			0.5			0.5	]			
VOL		$I_{OL} = 16 \text{ mA}$			0.4	0.4						
\ VOL	VCC = 3 V	$I_{OL} = 32 \text{ mA}$			0.5			0.5				
	ACC = 2 A	$I_{OL} = 48 \text{ mA}$	0.55				-					
		I <sub>OL</sub> = 64 mA				4			0.55			
	$V_{CC} = 0$ or $MAX^{\ddagger}$ ,	V <sub>I</sub> = 5.5 V		Ś	10			10				
 	V <sub>CC</sub> = 3.6 V	$V_I = V_{CC}$ or GND	Control inputs	Control inputs					±1	μΑ		
"		AI = ACC	Data inputs			1			1	μΑ		
		V <sub>I</sub> = 0	Data inputo		3	-5			-5			
l <sub>off</sub>	$V_{CC} = 0$ ,	$V_{I}$ or $V_{O} = 0$ to 4.5 \		5				±100	μΑ			
l(hold)	V <sub>CC</sub> = 3 V	V <sub>I</sub> = 0.8 V	Data inputs	75			75			μΑ		
'I(noid)	VCC = 0 V	V <sub>I</sub> = 2 V	Data inputo	-75			-75			μιτ		
I <sub>OZH</sub>	$V_{CC} = 3.6 \text{ V},$	V <sub>O</sub> = 3 V				5			5	μΑ		
I <sub>OZL</sub>	$V_{CC} = 3.6 \text{ V},$	V <sub>O</sub> = 0.5 V				-5			-5	μΑ		
	V <sub>CC</sub> = 3.6 V, V <sub>I</sub> = V <sub>CC</sub> or GND		Outputs high		0.12	0.19		0.12	0.19			
Icc		$I_{O} = 0$ ,	Outputs low		4.5	7		4.5	7	mA		
.00			Outputs disabled		0.12	0.19		0.12	0.19			
ΔI <sub>CC</sub> §	$V_{CC}$ = 3 V to 3.6 V, One input at $V_{CC}$ – 0.6 V, Other inputs at $V_{CC}$ or GND					0.3			0.2	mA		
C <sub>i</sub>	V <sub>I</sub> = 3 V or 0				4			4		pF		
Co	V <sub>O</sub> = 3 V or 0				8			8		pF		

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

<sup>§</sup> This is the increase in supply current for each input that is at the specified TTL voltage level rather than VCC or GND.



<sup>‡</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

# SN54LVT125, SN74LVT125 3.3-V ABT QUADRUPLE BUS BUFFERS WITH 3-STATE OUTPUTS

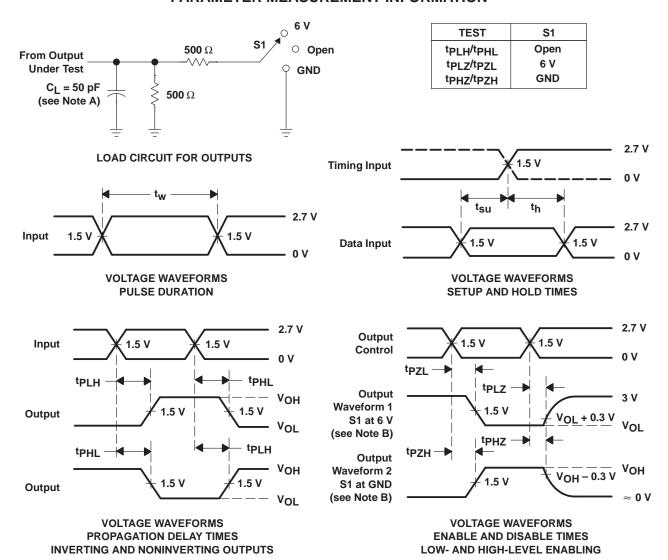
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# switching characteristics over recommended operating free-air temperature range, $C_L$ = 50 pF (unless otherwise noted) (see Figure 1)

			SN54LVT125				SN74LVT125									
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V			V <sub>CC</sub> = 2.7 V		UNIT				
			MIN	MAX	MIN	MAX	MIN	TYP <sup>†</sup>	MAX	MIN	MAX					
<sup>t</sup> PLH	А	А	۸	۸	۸	~	1	4.2	, N	4.7	1	2.7	4		4.5	no
<sup>t</sup> PHL			ı	1	4.1	BA	5.1	1	2.9	3.9		4.9	ns			
<sup>t</sup> PZH	ŌĒ		1	4.9	1	6.2	1	3.4	4.7		6	ns				
t <sub>PZL</sub>	OE	OE	'	1.1	4.9		6.7	1.1	3.4	4.7		6.5	115			
t <sub>PHZ</sub>	ŌĒ	ŌĒ	ŌĒ		1.8	5.3		5.9	1.8	3.7	5.1		5.7	20		
t <sub>PLZ</sub>				ī	1.3	4.7		4.2	1.3	2.6	4.5		4	ns		

 $<sup>\</sup>overline{\dagger}$  All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \ \Omega$ ,  $t_f \leq 2.5 \ ns$ .
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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